

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/836,426	04/17/2001	Tim Dyer	35013.4000	6845	
7590 03/08/2007 Snell & Wilmer LLP One Arizona Center			EXAMINER		
			MCDONALD, SHANTESE L		
400 E. Van Bu Phoenix, AZ 8			ART UNIT	PAPER NUMBER	
r nooma, ruz o.	, , , , , , , , , , , , , , , , , , ,		3723		
					
SHORTENED STATUTOR	RY PERIOD OF RESPONSE	MAIL DATE	DELIVERY MODE		
3 MO	PHTMC	03/08/2007	PAPER		

Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

	Application No.	Applicant(s)				
	09/836,426	DYER ET AL.				
Office Action Summary	Examiner	Art Unit				
	Shantese L. McDonald	3723				
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the o	correspondence address				
• •	(IO OET TO EVENE - MONTH	(0) 00 01 100 100 100 100 100 100 100 100				
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tir rill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	N. nely filed the mailing date of this communication. ED (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 30 No	ovember 2006.					
• • • • • • • • • • • • • • • • • • • •	_ ` `					
3) Since this application is in condition for allowar	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 4	53 O.G. 213.				
Disposition of Claims		·				
4) Claim(s) 1-33 is/are pending in the application.						
4a) Of the above claim(s) is/are withdraw						
5) Claim(s) is/are allowed.	÷					
6) Claim(s) <u>1-33</u> is/are rejected.						
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and/or	r election requirement.					
Application Papers						
	_					
9) The specification is objected to by the Examine10) The drawing(s) filed on is/are: a) access		Evaminer				
Applicant may not request that any objection to the						
Replacement drawing sheet(s) including the correcti		•				
11) The oath or declaration is objected to by the Ex						
Priority under 35 U.S.C. § 119						
_) (d) (f)'				
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:	priority under 35 U.S.C. § 119(a)-(a) or (t).				
1. ☐ Certified copies of the priority documents	s have been received.					
2.☐ Certified copies of the priority documents		ion No.				
3. Copies of the certified copies of the prior						
application from the International Bureau	ı (РСТ Rule 17.2(а)).					
* See the attached detailed Office action for a list	of the certified copies not receive	ed.				
•						
Attachment(s)						
1) Notice of References Cited (PTO-892)	4) Interview Summary					
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail D 5) Notice of Informal F					
3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	6) Other:	отоли фриосион				
		<u></u>				

Application/Control Number: 09/836,426

Art Unit: 3723

DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-9,26-29,32 and 33 are rejected under 35 U.S.C. 103(a) as being unpatentable over Breivogel et al. in view of Towery et al.

Breivogel et al. teaches a platen, 620, comprising a channel, 628, to allow polishing solution to circulate, for polishing a surface of a workpiece, the platen configured to orbit about an axis at a speed up to about 1000 or 2000 rpm, a polishing surface, 602, and to dither, attached to the platen and a workpiece carrier, 310, proximate the polishing surface, (col. 4, line 65-col.5, line 32). Breivogel teaches all the limitations of the claims except for the workpiece including a low dielectric material, the carrier and the platen being configured to move the workpiece relative to the polishing surface at a speed of about 0.8 to 3.2 m/s., the carrier configured to apply about 0.2 to about 2 pounds per square inch pressure to the workpiece, and the platen being configured to allow the polishing slurry to flow at a rate of about 120 to 200 ml/m. Towery et al. teaches CMP of a low k dielectric material, (col. 3, lines 41-55), with a platen configured to orbit, (col. 4, lines 25-30), and polishing with a surface speed of about 0.8 to 3.2 m/s, (col. 7, lines 60-67). It would have been obvious to one having ordinary skill in the art at the time the invention was made, to use the polisher of

Page 3

Art Unit: 3723

Breivogel et al. to polish the low k workpiece of Towery et al., since both inventions deal with polishing semiconductor workpieces with platens configured to orbit with dielectric materials, and since the Towery et al. reference teaches polishing the low k workpiece using chemical mechanical polishing. It would have been further obvious to provide the polishing system of Breivogel with the carrier configured to apply about 0.2 to about 2 pounds per square inch pressure to the workpiece, and the platen being configured to allow the polishing slurry to flow at a rate of about 120 to 200 ml/m, since the Breivogel reference teaches that one may change the parameters in order to optimize the polishing process for a specific application, (col. 8, lines 24-29).

Claim 10 is rejected under 35 U.S.C. 103(a) as being unpatentable over Breivogel et al. as modified by Towery et al. as applied to claim1-9,26-29,32 and 33 above, and further in view of Chen.

Breivogel et al. as modified by Towery et al. teaches all the limitations of the claims except for the carrier head including a bladder to regulate the pressure applied to the workpiece. Chen et al. teaches a bladder, 144. It would have been obvious to one having ordinary skill in the art at the time the invention was made, to provide the carrier head of Breivogel as modified by Towery et al. with a bladder, as taught by Chen, in order to more efficiently regulate the pressure applied to the workpiece.

Claims 11,30 and 31 are rejected under 35 U.S.C. 103(a) as being unpatentable over Breivogel et al. as modified by Towery et al. as applied to claims 1-9,26-29,32 and 33 above, and further in view of Kawamoto et al.

Page 4

Breivogel et al. as modified by Towery et al. teaches all the limitations of the claims except for the platen including a conduit configured to allow heat exchange fluid to flow through, to thereby regulate the temperature of the polishing surface and the polishing fluid. Kawamoto et al. teaches a conduit configured to allow heat exchange fluid to flow through, (col. 4, lines 25-36). It would have been obvious to one having ordinary skill in the art at the time the invention was made, to provide the polisher of Breivogel as modified by Towery et al., with a conduit to allow heat exchange, as taught by Kawamoto et al., in order to enhance the temperature control of the polishing system.

Claims 12,13,17-20,22,24 and 25 are rejected under 35 U.S.C. 103(a) as being unpatentable over Breivogel et al. as modified by Towery et al. as applied to claims 1-9,26-29,32 and 33 above, and further in view of Aizawa et al.

Breivogel et al. as modified by Towery et al. teaches all the limitations of the claims except for the polishing system comprising a plurality of polishing stations, clean station, a load station, and a buff station. Aizawa et al. teaches a plurality of polishing stations, 10a,b, clean stations, 26,a,b,c, a load station, 14, and a buff station, 200. Aizawa also teaches an orbital platen, (col. 5, lines 30-3). It would have been obvious to one having ordinary skill in the art to provide the polishing system of Breivogel et al.

as modified by Towery et al. with a plurality of polishing stations, clean station, a load station, and a buff station, as taught by Aizawa et al., in order to more efficiently and rapidly perform the polishing operations, and since both inventions deal with CMP utilizing a carrier and an orbital platen.

Claims 14-16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Breivogel as modified by Towery et al. and Alzawa and further in view of Chen.

Breivogel as modified by Towery et al. and Aizawa teaches all the limitations of the claims except for the system further comprising a carousel carrier apparatus, configured to rotate about an axis and translate in a radial direction. Chen teaches a carousel carrier apparatus, configured to rotate about an axis and translate in a radial direction, (col. 4, lines 16-20). It would have been obvious to one having ordinary skill in the art at the time the invention was made to provide the polishing system of Breivogel as modified by Towery et al. and Aizawa with the carousel carrier, in order to enhance the polishing efficiency.

Claims 21 and 23 are rejected under 35 U.S.C. 103(a) as being unpatentable over Breivogel as modified by Towery et al. and Aizawa, and further in view of Kawamoto et al.

Breivogel as modified by Towery et al. and Aizawa teaches all the limitations fo the claims except for the polishing system comprising a temperature control system in the form of grooves in the platen to allow heat exchange fluid to flow through a portion Art Unit: 3723

of the platen. Kawamoto et al. teaches grooves in the platen to allow heat exchange fluid to flow through a portion of the platen, (col. 4, lines 25-36). It would have been obvious to one having ordinary skill in the art at the time the invention was made, to provide the polishing system of Breivogel as modified by Towery et al. and Aizawa with a conduit to allow heat exchange, as taught by Kawamoto et al., in order to enhance the temperature control of the polishing system.

Response to Arguments

Applicant's arguments filed 11/30/06 have been fully considered but they are not persuasive.

The Applicant argues that there is not motivation to combine the Brievogel and the Towery references. The Examiner disagrees. The Brievogel reference teaches an orbiting platen, (col. 4, line 65-col. 5, line 32). Brievogel also teaches that the pad orbits at a rate of between 140 –220 orbits/minute. The present invention claims a pad that orbits at a speed "up to" about 2000 revolution/orbit per min. The claim language of "up to" means that it can fall anywhere in a range from 0 to 2000 orbits/min, and therefore the rate of 140-220 orbits/min, as taught by Brievogel would fall in this range.

The Towery reference teaches an oxidizing slurry for the removal of low dielectric, (low-k), constant material, (col. 3, lines 41-42). Towery also teaches that the oxidizing slurry of the present invention, which is for the removal of low-k material, can be utilized with any type of CMP device, such as an orbital CMP device, (col. 4, lines 25-30).

Art Unit: 3723

The invention of Brievogel is a CMP operation in which the polishing takes place while the platen orbits, and therefore it is a orbital CMP operation. The invention of Towery teaches a CMP method in which a slurry for removing low-k material is utilized. Towery goes on to state that the slurry of his invention can be utilized in various CMP methods, including orbital CMP operations. Therefore, one could utilize the slurry of Towery, which is for low-k materials in the polishing operation of Brievogel in order to remove low-k materials. In reference to the various polishing parameters, Brievogel teaches that one may change the polishing parameters in order to optimize the polishing process for a specific application, (col. 8, lines 24-29). In this instance, the specific application would be for the removal of low-k material. Also, it is definitely a know fact in the art that, where the general conditions of a claim are disclosed in the prior art, discovering the optimum or workable ranges involves only routine skill in the art.

Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any

Application/Control Number: 09/836,426 Page 8

Art Unit: 3723

extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Shantese L. McDonald whose telephone number is (571) 272-4486. The examiner can normally be reached on 8:00 a.m. - 4:30 p.m..

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Joseph Hail can be reached on (571) 272-4485. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

S.L.M. March 5, 2007

Joseph J. Hail, III Supervisory Patent Examiner Technology Center 3700